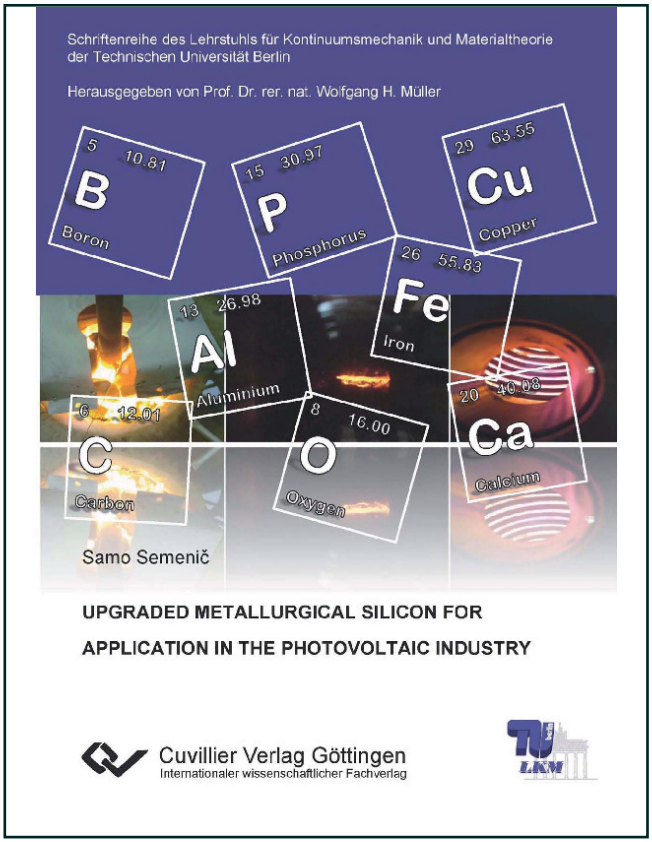
Samo Semenic (Autor)

Upgraded metallurgical silicon for application in the photovoltaic industry



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